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Examiner: Fernando L. Toldeo

From: Yongzhi Yang

6/30/2006

To: Art Unit: 2823

571-273-8300 Fax:

Pages: 13 pages including fax cover sheet

Phone:

Re:

U.S. Patent Appln. 10/659,949

Filed: September 11, 2003

Docket: YOR920020182US2 (15790A)

Confirmation No. 5877

RESPONSE TO OFFICE ACTION

Date:

CC:

Please see the following documents:

- 1. Amendment Transmittal (in duplicate)
- 2. Authorization to charge IBM deposit account
- 3. Response Under 37 C.F.R. § 1.111 (9 pages)
- 4. Certificate of transmission by facsimile dated June 30, 2006

If you have any questions concerning this facsimile please contact Vivian Henriquez at 516-742-4343. Thank you.

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2/ 13

JUN 3 0 2006

CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8) Applicant(s): Hussein L Hanafi et al.			Docket No. YOR920020182US2 (15790A)
Application No. 10/659,949	Filing Date September 11, 2003	Examiner Fernando L. Toledo	Group Art Unit 2823
Invention: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN INNOVATIVE OXIDE REMOVAL ETCH			
I hereby certify that this Response under 37 C.F.R. §1.111 (Identify type of correspondence) is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. 571-273-8300			
on June 30, 2		and Hademark Office (Fax.)	VV. 5/1-2/3-6300
		Yongzhi Y (Typed or Printed Name of Perso O (Signature	on Signing Certificate)
	Note: Each paper must hav	ve its own certificate of mailing.	

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IUN 3 0 2006 AMENDMENT TRANSMITTAL LETTER (Large Entity) Docket No. Applicant(s): Hussein I. Hanafi et al. YOR920020182US2(15790A) Application No. Customer No. Filing Date Examiner Group Art Unit Confirmation No. 10/659,949 September 11, 2003 23389 2823 5877 Fernando L. Toldeo LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN invention: INNOVATIVE OXIDE REMOVAL ETCH **COMMISSIONER FOR PATENTS:** Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below. CLAIMS AS AMENDED **CLAIMS REMAINING** HIGHEST # NUMBER EXTRA **ADDITIONAL** RATE AFTER AMENDMENT PREV. PAID FOR CLAIMS PRESENT FEE **TOTAL CLAIMS** 6 20 \$50.00 \$0.00 0 х INDEP. CLAIMS 2 0 = X \$200.00 \$0.00 \$0.00 Multiple Dependent Claims (check if applicable) \$0.00 TOTAL ADDITIONAL FEE FOR THIS AMENDMENT No additional fee is required for amendment. ☐ Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17. ☐ Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be Included on this form. Provide credit card information and authorization on PTO-2038. Dated: June 30, 2006 Signature Yongzhi Yang Registration No. 56,310 I hereby certify that this correspondence is being deposited with SCULLY, SCOTT, MURPHY & PRESSER, P.C. the United States Postal Service with sufficient postage as first class mail-in an envelope addressed to "Commissioner for Patents, 400 Garden City Plaza - Suite 300 P.O. Box 1450, Alexandria, VA 22313-1450 (87 CFR 1.8(a)) on Garden City, New York 11530 (Date) Signature of Person Mailing Correspondence CC: Typed or Printed Name of Person Mailing Correspondence

JUN 3 0 2006

AMENDMENT TRANSMITTAL LETTER (Large Entity) Docket No. Applicant(s): Hussein I. Hanafi et al. YOR920020182US2(15790A) Application No. Customer No. Group Art Unit Filing Date Examiner Confirmation No. 10/659,949 September 11, 2003 Fernando L. Toldeo 23389 2823 5877 LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN Invention: INNOVATIVE OXIDE REMOVAL ETCH **COMMISSIONER FOR PATENTS:** Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below. CLAIMS AS AMENDED **CLAIMS REMAINING** HIGHEST # NUMBER EXTRA **ADDITIONAL** RATE **CLAIMS PRESENT** AFTER AMENDMENT PREV. PAID FOR FEE **TOTAL CLAIMS** 6 20 \$50.00 \$0.00 X INDEP. CLAIMS 2 3 0 \$200.00 x \$0.00 Multiple Dependent Claims (check if applicable) \$0.00 \$0.00 TOTAL ADDITIONAL FEE FOR THIS AMENDMENT No additional fee is required for amendment. Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17. Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038. Dated: June 30, 2006 Signature Yongzhi Yang Registration No. 56,310 I hereby certify that this correspondence is being deposited with SCULLY, SCOTT, MURPHY & PRESSER, P.C. the United States Postal Service with sufficient postage as first class mail in an envelope addressed to "Comprissioner for Patents, 400 Garden City Plaza - Suite 300 P.O. Box 1459, Alexandria, VA 22313-1450 [37 CFR 1.8(a)] on Garden City, New York 11530 (Date) Signature of Person Mailing Correspondence cc: Typed or Printed Name of Person Mailing Correspondence

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Hussein I. Hanafi et al.

Docket:

YOR920020182US2

(15790A)

Serial No.:

10/659,949

Examiner:

Fernando L. Toldeo

Filed:

September 11, 2003

Art Unit:

2823

For:

LOW RESISTANCE T-GATE

Dated:

June 30, 2006

MOSFET DEVICE USING A

DAMASCENE GATE PROCESS

AND AN INNOVATIVE OXIDE

REMOVAL ETCH

Confirmation No:

5877

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. § 1.111

Sir:

In response to the Office Action dated April 3, 2006, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this document is being filed in the United States Patent and Trademark Office on the date shown below via facsimile transmission to Mail Stop Amendment, Commissioner for Patents, PO Box 1450, Alexandria, VA 22313-1450 at United States Patent and Trademark Office facsimile transmission number (571) 273-8300.

Dated: June 30, 2006

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